

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-20	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 6) Continuous T _A = +25°C T _A = +70°C	I _D	-3.0 -2.4	A
Pulsed Drain Current (Note 7)	I _{DM}	-15	A
Body-Diode Continuous Current (Note 6)	I _S	-2.0	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P _D	1.4	W
Thermal Resistance, Junction to Ambient (Note 6); Steady-State	R _{θJA}	90	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
STATIC PARAMETERS						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	—	V	I _D = -250μA, V _{GS} = 0V
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	—	—	-1	μA	V _{DS} = -20V, V _{GS} = 0V
Gate-Body Leakage Current	I _{GSS}	—	—	±100	nA	V _{DS} = 0V, V _{GS} = ±12V
Gate Threshold Voltage	V _{GS(TH)}	-0.6	—	-1.25	V	V _{DS} = V _{GS} , I _D = -250μA
On State Drain Current (Note 8)	I _{D(ON)}	-15	—	—	A	V _{GS} = -4.5V, V _{DS} = -5V
Static Drain-Source On-Resistance (Note 8)	R _{DS(ON)}	—	51 87 99	72 108 123	mΩ	V _{GS} = -4.5V, I _D = -3.5A V _{GS} = -2.7V, I _D = -3.0A V _{GS} = -2.5V, I _D = -2.6A
Forward Transconductance (Note 8)	g _{FS}	—	7.3	—	S	V _{DS} = -10V, I _D = -3.0A
Diode Forward Voltage (Note 6)	V _{SD}	—	-0.79	-1.26	V	I _S = -1.7A, V _{GS} = 0V
Maximum Body-Diode Continuous Current (Note 6)	I _S	—	—	-1.7	A	—
DYNAMIC PARAMETERS (Note 9)						
Total Gate Charge	Q _g	—	7.3	—	nC	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -3.0A
Gate-Source Charge	Q _{gs}	—	2.0	—	nC	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -3.0A
Gate-Drain Charge	Q _{gd}	—	1.9	—	nC	V _{GS} = -4.5V, V _{DS} = -10V, I _D = -3.0A
Turn-On Delay Time	t _{D(ON)}	—	12	—	ns	V _{DS} = -10V, V _{GS} = -4.5V, R _L = 10Ω, R _G = 6Ω
Turn-On Rise Time	t _R	—	20	—	ns	
Turn-Off Delay Time	t _{D(OFF)}	—	38	—	ns	
Turn-Off Fall Time	t _F	—	41	—	ns	
Input Capacitance	C _{iss}	—	443	—	pF	V _{DS} = -16V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	128	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	101	—	pF	

- Notes:
6. Device mounted on 1" x 1", FR-4 PC board with 2 oz. copper and test pulse width t ≤ 10s.
 7. Repetitive Rating, pulse width limited by junction temperature.
 8. Test pulse width t = 300μs.
 9. Guaranteed by design. Not subject to product testing.

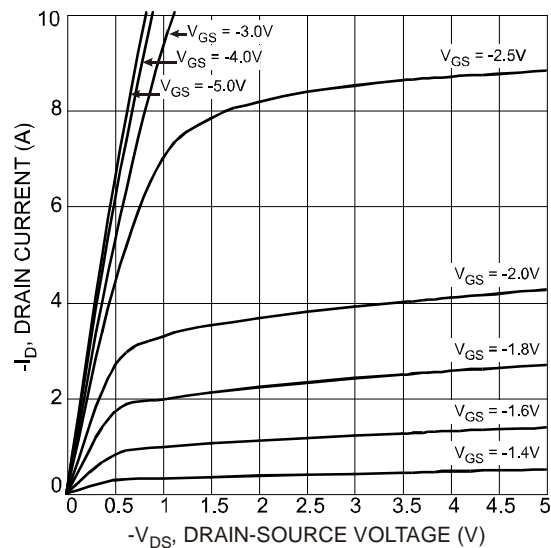


Fig. 1 Typical Output Characteristics

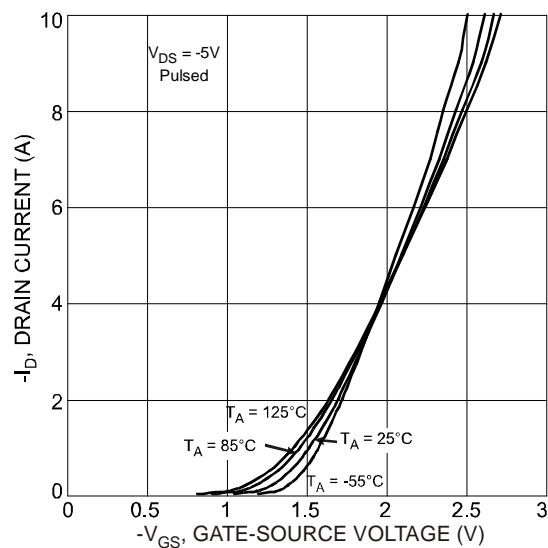


Fig. 2 Typical Transfer Characteristics

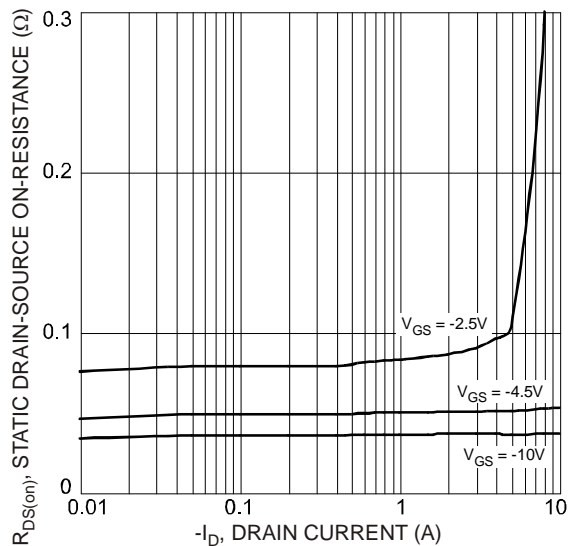


Fig. 3 On-Resistance vs. Drain Current and Gate Voltage

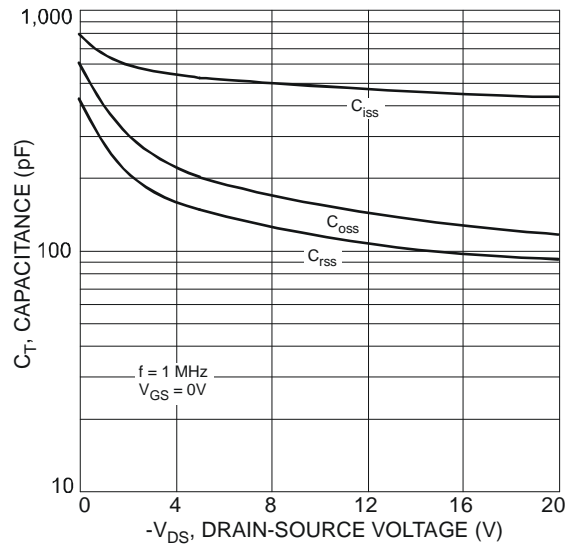


Fig. 4 Typical Total Capacitance

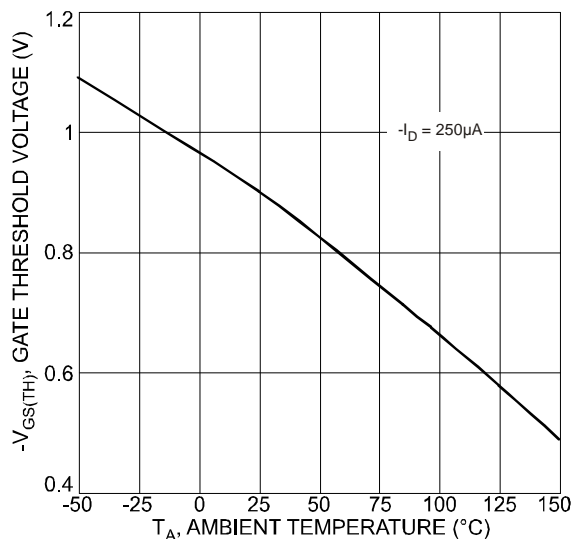


Fig. 5 Gate Threshold Voltage vs. Ambient Temperature

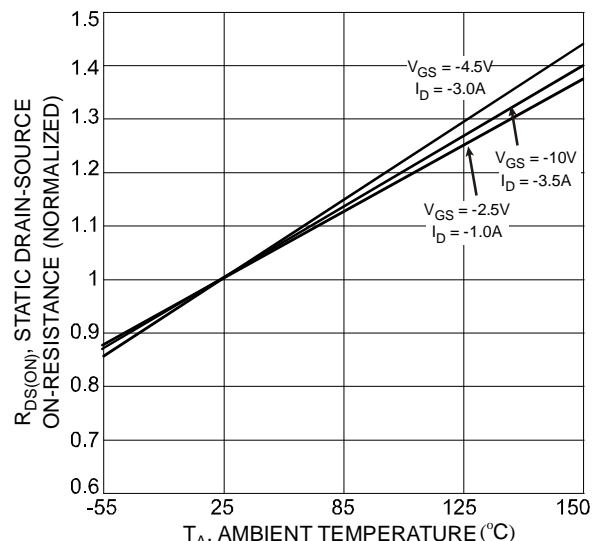


Fig. 6 Normalized Static Drain-Source On-Resistance vs. Ambient Temperature

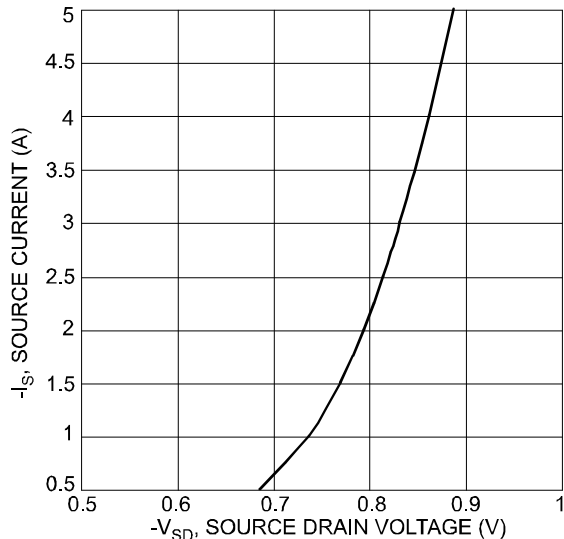


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

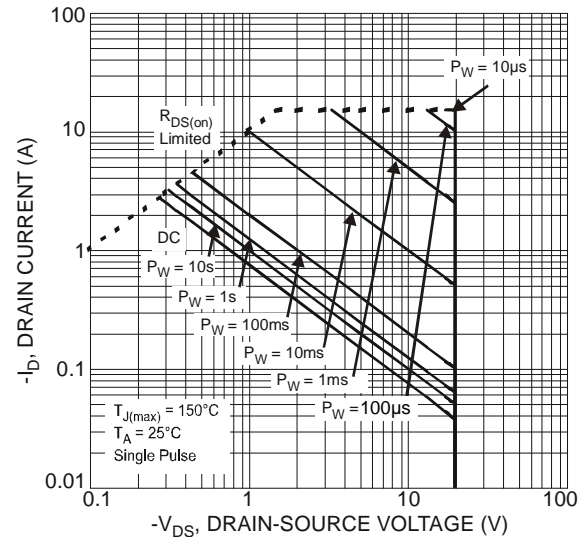
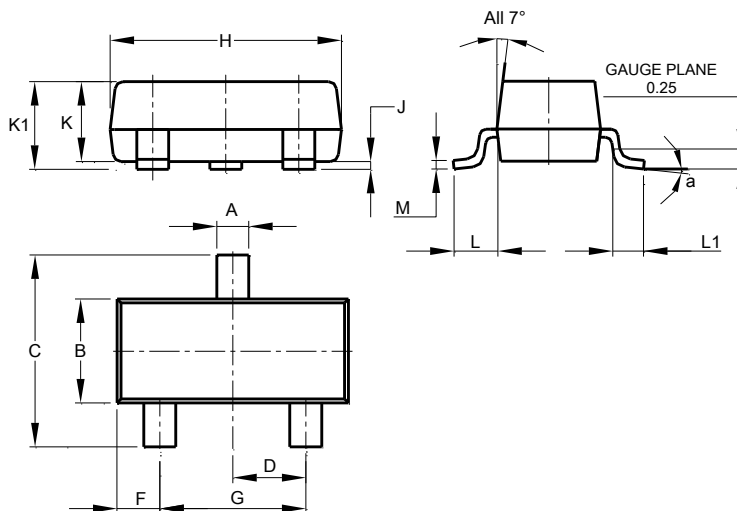


Fig. 8 SOA, Safe Operation Area

Package Outline Dimensions

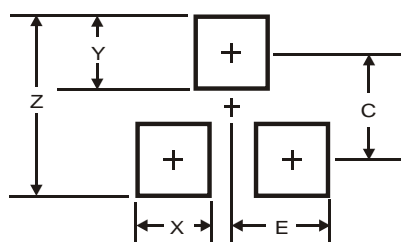
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	8°		
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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